

### **Features**

- Ideal for Medium Power Amplification and Switching
- Ultra Low Collector-Emitter Saturation Voltage
- Lead, Halogen and Antimony Free, RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- ESD rating: 400V-MM, 8KV-HBM

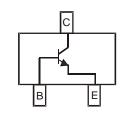
### **Mechanical Data**

- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.008 grams (approximate)





Device Symbol



Pin Configuration

### **Ordering Information**

Part Number	Case	Packaging
DSS30101L-7	SOT-23	3000/Tape & Reel

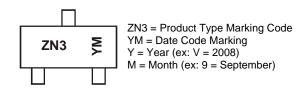
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Notes: 1. No purposefully added lead. Halogen and Antimony Free.

2. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com

## **Marking Information**



Date Code Key 2008 2009 2010 2011 2012 2013 2014 2015 Year V W Х Ζ В С Code Y A Month Jan Feb Mar Apr May Jun Jul Aug Sep Oct Nov Dec Code 0 D 2 3 8 9 Ν 1 4 5 6 7



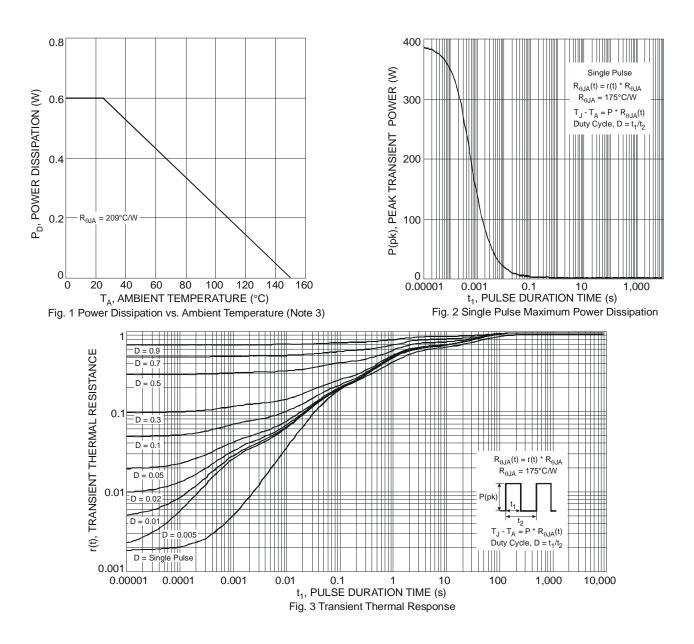
## **Maximum Ratings** $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	30	V
Emitter-Base Voltage	V <sub>EBO</sub>	5	V
Peak Pulse Current	I <sub>CM</sub>	2	А
Continuous Collector Current	Ic	1	А

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @ T <sub>A</sub> = 25°C	PD	600	mW
Thermal Resistance, Junction to Ambient Air (Note 3) @ $T_A = 25^{\circ}C$	$R_{ ext{ heta}JA}$	209	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes: 3. Device mounted on FR-4 PCB MRP

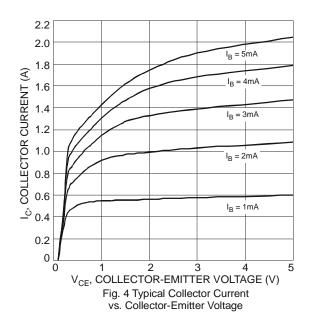


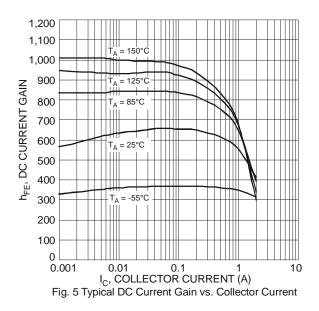


# Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions	
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	50	_		V	$I_C = 100 \mu A$	
Collector-Emitter Breakdown Voltage (Note 4)	V <sub>(BR)CEO</sub>	30	_		V	$I_{\rm C} = 10 {\rm mA}$	
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	5	_		V	I <sub>E</sub> = 100μA	
Collector-Base Cutoff Current		_	_	100	nA	$V_{CB} = 30V, I_E = 0$	
	I <sub>CBO</sub>	_	_	50	μΑ	$V_{CB} = 30V, I_E = 0, T_A = 150^{\circ}C$	
Emitter-Base Cutoff Current	I <sub>EBO</sub>	_	_	100	nA	$V_{EB} = 4V, I_{C} = 0$	
		300	_			$V_{CE} = 5V, I_{C} = 50mA$	
DC Current Gain (Note 4)	h <sub>FE</sub>	300	450	900	_	$V_{CE} = 5V, I_{C} = 0.5A$	
		200	_			$V_{CE} = 5V, I_C = 1A$	
		_	_	75	75 125 mV 200	$I_{\rm C} = 0.1 \text{A}, I_{\rm B} = 1 \text{mA}$	
Collector-Emitter Saturation Voltage (Note 4)	V <sub>CE(sat)</sub>	_	_	125		$I_{C} = 0.5A, I_{B} = 50mA$	
		_	—	200		$I_{\rm C} = 1.0$ A, $I_{\rm B} = 100$ mA	
Equivalent On-Resistance (Note 4)	R <sub>CE(sat)</sub>	_	_	200	mΩ	I <sub>E</sub> = 1A, I <sub>B</sub> = 100mA	
Base-Emitter Saturation Voltage (Note 4)	V <sub>BE(sat)</sub>	_	0.93	1.1	V	$I_{C} = 1A, I_{B} = 100 \text{mA}$	
Base-Emitter Turn-on Voltage (Note 4)	V <sub>BE(on)</sub>	_	0.80	1.1	V	$V_{CE} = 2V, I_{C} = 1A$	
Transition Frequency	f <sub>T</sub>	100	250		MHz	$V_{CE} = 5V, I_C = 100mA,$ f = 100MHz	
Output Capacitance	C <sub>obo</sub>	_	9	15	pF	$V_{CB} = 10V, f = 1MHz$	
Input Capacitance	C <sub>ibo</sub>	_	65	—	pF	$V_{EB} = 5V$ , f = 1MHz	
Turn-On Time	t <sub>on</sub>	_	57	_	ns		
Delay Time	t <sub>d</sub>	_	19	_	ns	]	
Rise Time	tr	_	38		ns	$V_{CC} = 5V, I_{C} = 500 \text{mA},$	
Turn-Off Time	t <sub>off</sub>	_	340		ns	$I_{B1} = -I_{B2} = 50 \text{mA}$	
Storage Time	ts	_	315		ns	]	
Fall Time	t <sub>f</sub>	_	25	_	ns	]	

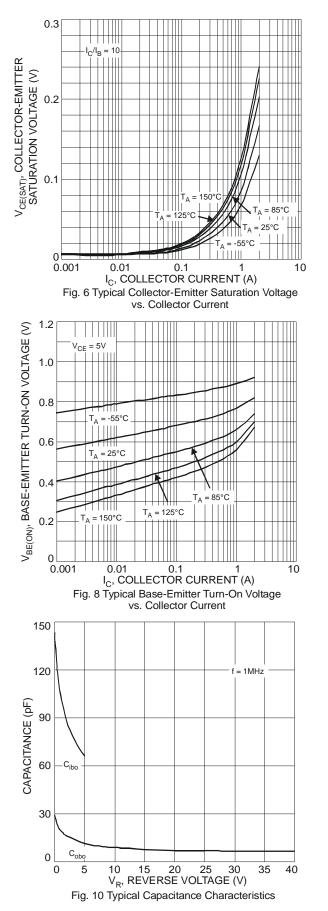
Notes: 4. Measured under pulsed conditions. Pulse width =  $300\mu$ s. Duty cycle  $\leq 2\%$ .

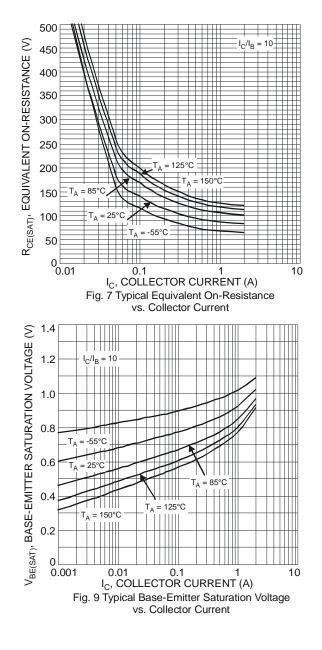






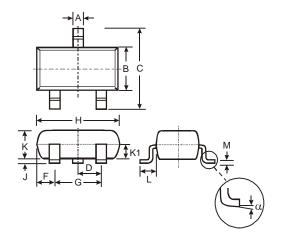






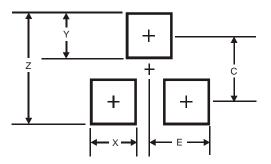


# Package Outline Dimensions



	SOT-23				
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
ĸ	0.903	1.10	1.00		
K1	-	-	0.400		
L	0.45	0.61	0.55		
М	0.085	0.18	0.11		
α	0°	8°	-		
All	All Dimensions in mm				

# Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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